Electron charge decoherence due to electron-phonon coupling in a semiconductor double quantum dot

VASILIOS STAVROU, XUEDONG HU, Department of Physics, State University of New York, Buffalo, NY 14260-1500 — We have studied single electron charge relaxation and dephasing rates in laterally coupled GaAs double quantum dot due to electron-phonon interaction. We first calculate the single electron wavefunctions in the double dot using a basis formed by the Fock-Darwin states. For the electron-phonon interaction we include both deformation potential and piezoelectric coupling. Our results show strong dependence of the relaxation and dephasing rates on interdot distance, confinement strength, and interdot bias.

Vasilios Stavrou
Department of Physics, State University of New York
Buffalo, NY 14260-1500

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